imall

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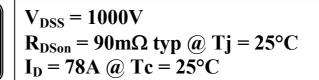
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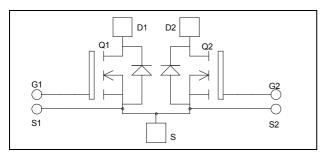
Tel: +86-755-8981 8866 Fax: +86-755-8427 6832 Email & Skype: info@chipsmall.com Web: www.chipsmall.com Address: A1208, Overseas Decoration Building, #122 Zhenhua RD., Futian, Shenzhen, China

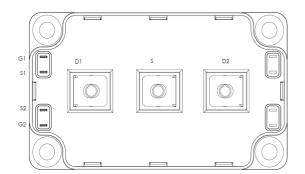




Dual Common Source MOSFET Power Module







Application

- AC Switches
- Switched Mode Power Supplies
- Uninterruptible Power Supplies

Features

- Power MOS 7[®] MOSFETs
 - Low R_{DSon}
 - Low input and Miller capacitance
 - Low gate charge
 - Avalanche energy rated
 - Very rugged
 - Kelvin source for easy drive
 - Very low stray inductance
 - Symmetrical design
 - M5 power connectors
 - High level of integration

Benefits

- Outstanding performance at high frequency operation
- Direct mounting to heatsink (isolated package)
- Low junction to case thermal resistance
- Low profile
- RoHS Compliant

Absolute maximum ratings

Symbol	Parameter		Max ratings	Unit
V _{DSS}	Drain - Source Breakdown Voltage		1000	V
Т	Continuous Drain Current	$T_c = 25^{\circ}C$	78	
I _D	Continuous Drain Current	$T_c = 80^{\circ}C$	59	А
I _{DM}	Pulsed Drain current	312		
V _{GS}	Gate - Source Voltage		±30	V
R _{DSon}	Drain - Source ON Resistance		105	mΩ
P _D	Maximum Power Dissipation	$T_c = 25^{\circ}C$	1250	W
I _{AR}	Avalanche current (repetitive and non repetitive)		25	А
E _{AR}	Repetitive Avalanche Energy		50	mJ
E _{AS}	Single Pulse Avalanche Energy		3000	IIIJ

CAUTION: These Devices are sensitive to Electrostatic Discharge. Proper Handling Procedures Should Be Followed. See application note APT0502 on www.microsemi.com



All ratings (a) $T_j = 25^{\circ}C$ unless otherwise specified

Electrical Characteristics

Symbol	Characteristic	Test Conditions		Min	Тур	Max	Unit	
I _{DSS}	Zero Gate Voltage Drain Current	$V_{GS} = 0V, V_{DS} = 1000V$	$T_j = 25^{\circ}C$			400		
		$V_{GS} = 0V, V_{DS} = 800V$	$T_j = 125^{\circ}C$			2000	μA	
R _{DS(on)}	Drain – Source on Resistance	$V_{GS} = 10V, I_D = 39A$			90	105	mΩ	
V _{GS(th)}	Gate Threshold Voltage	$V_{GS} = V_{DS}, I_D = 10 \text{mA}$		3		5	V	
I _{GSS}	Gate – Source Leakage Current	$V_{GS} = \pm 30 \text{ V}, V_{DS} = 0 \text{ V}$	r			±250	nA	

Dynamic Characteristics

Symbol	Characteristic	Test Conditions	Min	Тур	Max	Unit
C _{iss}	Input Capacitance	$V_{GS} = 0V$		20.7		
Coss	Output Capacitance	$V_{\rm DS} = 25 V$		3.5		nF
C _{rss}	Reverse Transfer Capacitance	f = 1MHz		0.64		
Qg	Total gate Charge	$V_{GS} = 10V$		744		nC
Q _{gs}	Gate – Source Charge	$V_{Bus} = 500V$		96		
Q_{gd}	Gate – Drain Charge	$I_D = 78A$		488		
T _{d(on)}	Turn-on Delay Time	Inductive switching @ 125°C $V_{GS} = 15V$ $V_{Bus} = 670V$ $I_D = 78A$ $R_G = 1.2\Omega$		18		ns
Tr	Rise Time			12		
T _{d(off)}	Turn-off Delay Time			155		
$T_{\rm f}$	Fall Time			40		
Eon	Turn-on Switching Energy	Inductive switching @ 25°C $V_{GS} = 15V$, $V_{Bus} = 670V$ $I_D = 78A$, $R_G = 1.2\Omega$		3.6		T.
$\mathrm{E}_{\mathrm{off}}$	Turn-off Switching Energy			2.5		mJ
Eon	Turn-on Switching Energy	Inductive switching @ 125°C $V_{GS} = 15V$, $V_{Bus} = 670V$ $I_D = 78A$, $R_G = 1.2\Omega$		5.7		J
$\mathrm{E}_{\mathrm{off}}$	Turn-off Switching Energy			3.1		mJ

Source - Drain diode ratings and characteristics

Symbol	Characteristic	Test Conditions		Min	Тур	Max	Unit
Is	Continuous Source current		$Tc = 25^{\circ}C$			78	А
	(Body diode)		$Tc = 80^{\circ}C$			59	Л
V_{SD}	Diode Forward Voltage	$V_{GS} = 0V, I_S = -78A$				1.3	V
dv/dt	Peak Diode Recovery 1					10	V/ns
t _{rr}	Reverse Recovery Time	$I_{\rm S} = -78 {\rm A}, {\rm V}_{\rm R} = 670 {\rm V}$			1170		ns
Q _{rr}	Reverse Recovery Charge	$di_{s}/dt = 400A/\mu s$			65.1		μC

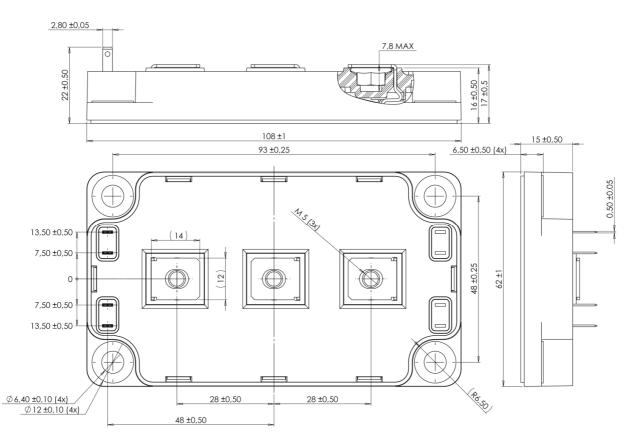
• dv/dt numbers reflect the limitations of the circuit rather than the device itself. $I_S \le -78A$ di/dt $\le 700A/\mu s$ $V_R \le V_{DSS}$ $T_i \le 150^{\circ}C$



Thermal and package characteristics

Symbol	Characteristic			Min	Тур	Max	Unit
R _{thJC}	Junction to Case Thermal Resistance					0.1	°C/W
V _{ISOL}	RMS Isolation Voltage, any terminal to case t =1 min, 50/60Hz			4000			V
TJ	Operating junction temperature range			-40		150	°C
T _{STG}	Storage Temperature Range			-40		125	
T _C	Operating Case Temperature			-40		100	
Torque	Mounting torque	To heatsink	M6	3		5	N.m
		For terminals	M5	2		3.5	19.111
Wt	Package Weight					300	g

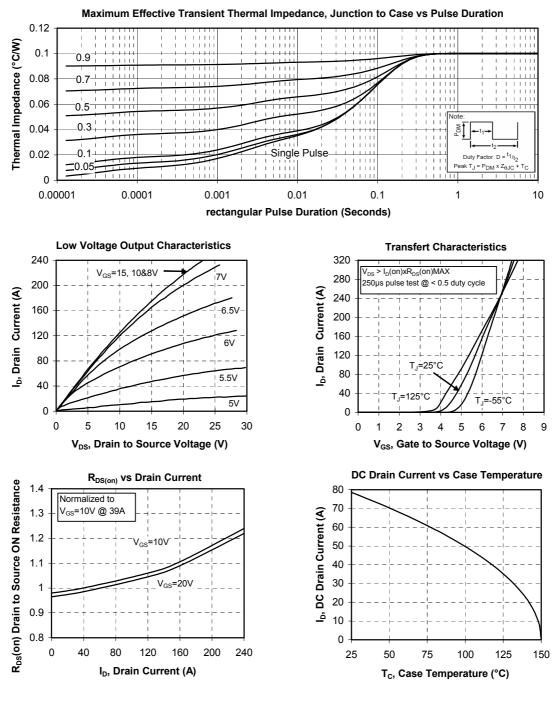
SP6 Package outline (dimensions in mm)



See application note APT0601 - Mounting Instructions for SP6 Power Modules on www.microsemi.com

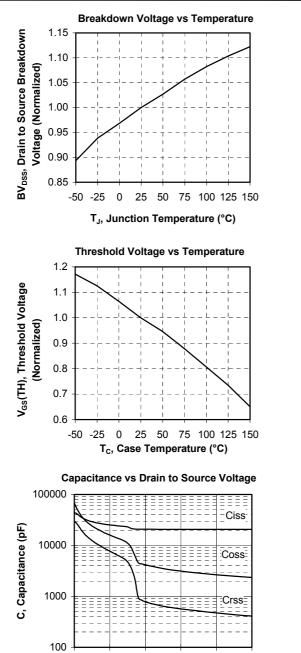


Typical Performance Curve



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10

20

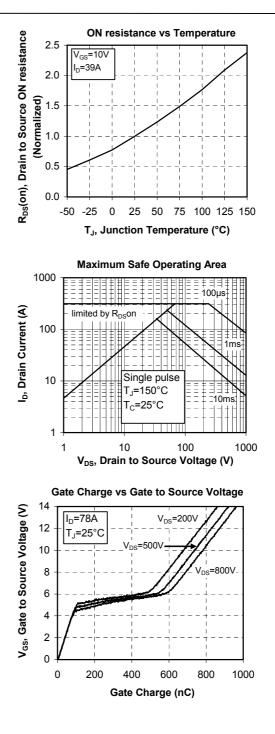
V_{DS}, Drain to Source Voltage (V)

30

50

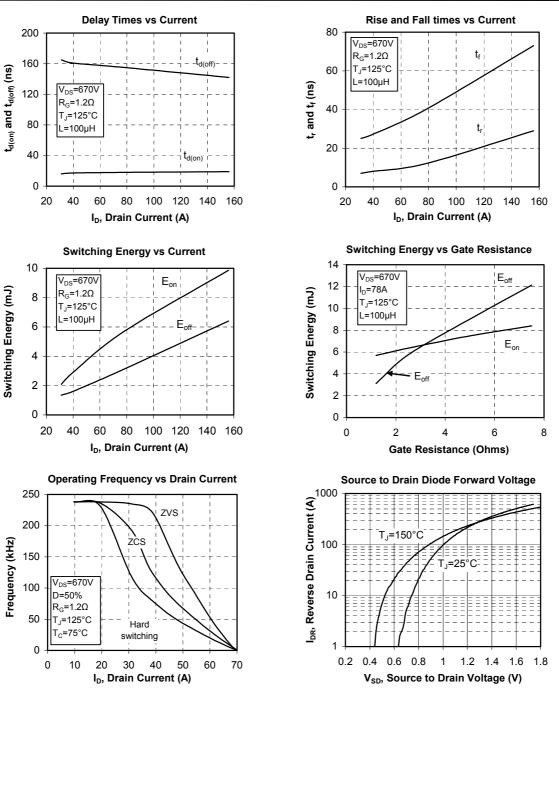
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APTM100DUM90G



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